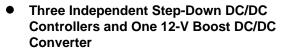
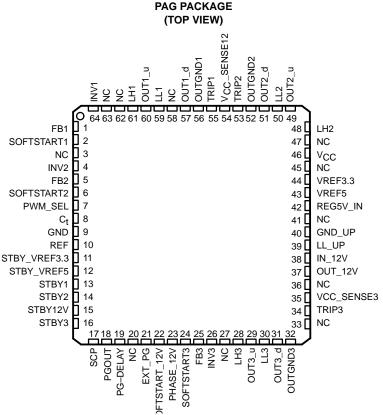
# TPS5140 FOUR-CHANNEL DC/DC CONTROLLER FOR NOTEBOOK PC POWER

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- 4.5 V 28 V Input Voltage Range
- Step-Down Controller Output Voltages Adjustable Down to 1.2 V
- Synchronous-Buck Operation for High Efficiency
- PWM Mode Control
- Auto PWM/SKIP Mode for High Efficiency Under All Load Conditions
- High Speed Error Amplifier
- Separate Standby Control and Over Current Protection for Each Channel
- Over Voltage and Under Voltage Protection
- Programmable Short Circuit Protection
- Power Good With Programmable Delay Time
- 5 V and 3.3 V Linear Regulators



#### description

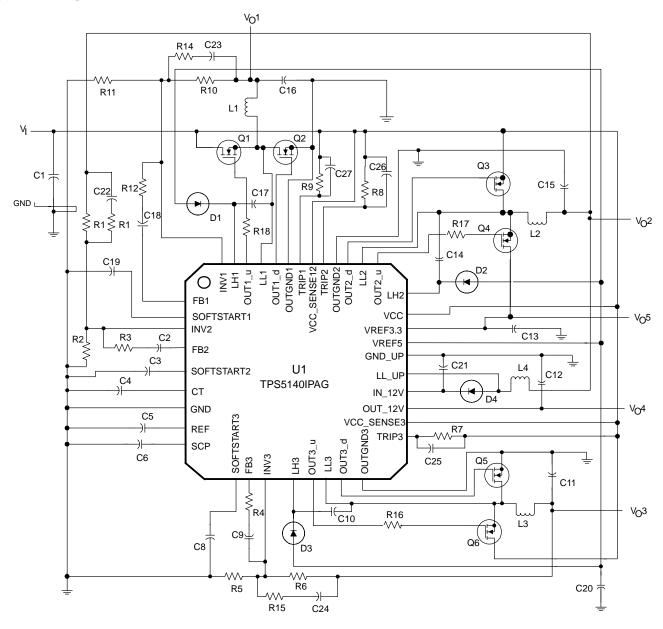
The TPS5140 is a dc/dc controller that incorporates three synchronous-buck controllers and one nonsynchronous 12-V boost converter on one chip to power the voltage rails needed by notebook peripheral components. On-chip high-side and low-side synchronous rectifier drivers are integrated to drive less expensive N-channel power MOSFETs. The nonsynchronous boost converter includes the N channel power MOSFET and supports 120 mA for the PCMCIA power supply. The outputs are controlled independently and two of the synchronous-buck controllers operate 180 degrees out of phase, with the third lowering the input current ripple and allowing a smaller input capacitance to reduce power supply cost. For higher efficiency under all load conditions, the TPS5140 automatically adjusts each channel from the PWM mode to the skip mode independently. The skip mode enables a lower operating frequency and shortens the pulse width to the low side MOSFETs, thereby increasing the efficiency under light load conditions. To further extend battery life, the TPS5140 features dead-time control and very low quiescent current. Resistorless current protection and the fixed high-side driver voltage simplify the system design and reduce the external parts count.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



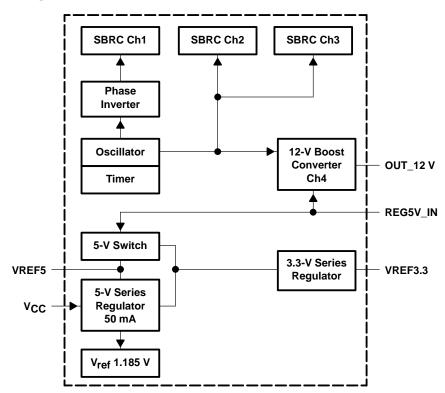
#### typical design schematic



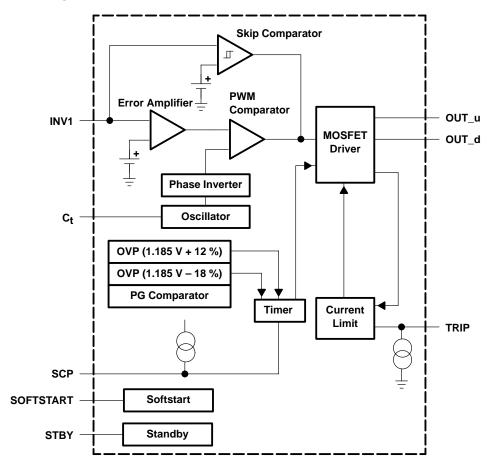
#### **AVAILABLE OPTIONS**

т.	PACKAGE		
'A	PAG	EVM	
-20°C to 85°C	TQFP64 (PAG)		

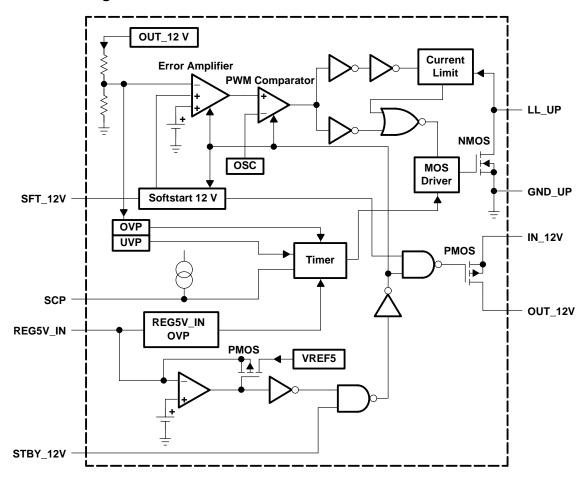
## functional block diagram—whole block



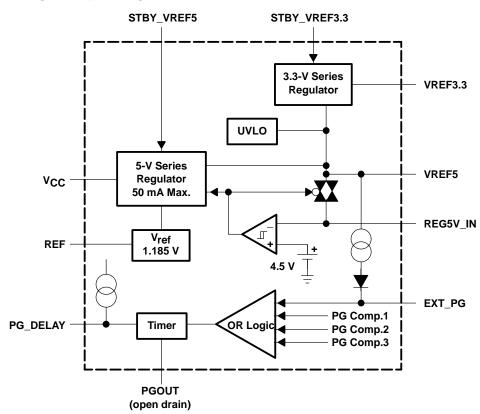
#### functional block diagram—SMPS block



## functional block diagram—boost 12-V block



#### functional block diagram—power good block



#### **Terminal Functions**

TERMINAL			
NAME	NO.	1/0	DESCRIPTION
Ct	8	I/O	External capacitor from C <sub>t</sub> to GND used for adjusting the triangle oscillator.
EXT_PG	21	-	External power good signal input
FB1	1	0	Feedback output of CH1 error amplifier
FB2	5	0	Feedback output of CH2 error amplifier
FB3	25	0	Feedback output of CH3 error amplifier
GND	9		Control GND
GND_UP	40		Ground for 12-V boost converter
INV1	64	ı	Inverting input of CH1 error amplifier, skip comparator and OVP1/UVP1, PG comparator
INV2	4	ı	Inverting input of CH1 error amplifier, skip comparator and OVP2/UVP2, PG comparator
INV3	26	ı	Inverting input of CH1 error amplifier, skip comparator and OVP3/UVP3, PG comparator
IN_12V	38	I	Input of PMOS switch for 12-V boost output. Connecting to cathode of the external Schottky diode.
LH1	61	I/O	Bootstrap capacitor connection for CH1 high side gate drive
LH2	48	I/O	Bootstrap capacitor connection for CH2 high side gate drive
LH3	28	I/O	Bootstrap capacitor connection for CH3 high side gate drive
LL1	59	I/O	Bootstrap low for CH1 high side gate driving return and output current protection. Connect to the junction of the high side and low side FETs for floating drive configuration.
LL2	50	I/O	Bootstrap low for CH2 high side gate driving return and output current protection. Connect to the junction of the high side and low side FETs for floating drive configuration.
LL3	30	I/O	Bootstrap low for CH3 high side gate driving return and output current protection. Connect to the junction of the high side and low side FETs for floating drive configuration.
LL_UP	39	I/O	Open drain output of internal NMOS switch for 12-V boost converter. Connect between external inductor and the anode of the schottky diode.
NC	3,20,27,33, 36,41,45,47 58,62,63		No connect
OUT1_d	57	0	Gate drive output for CH1 low side gate drive
OUT2_d	51	0	Gate drive output for CH2 low side gate drive
OUT3_d	31	0	Gate drive output for CH3 low side gate drive
OUT1_u	60	0	Gate drive output for CH1 high side switching FETs
OUT2_u	49	0	Gate drive output for CH2 high side switching FETs
OUT3_u	29	0	Gate drive output for CH3 high side switching FETs
OUT_12V	37	0	Output of PMOS switch for 12-V boost output. Connect to the output capacitor for 12-V boost output.
OUTGND1	56		Ground for CH1 FETs drivers. It is connected to one of the current limiting comparator input.
OUTGND2	52		Ground for CH2 FETs drivers. It is connected to one of current limiting comparator input.
OUTGND3	32		Ground for CH3 FETs drivers. It is connected to the one of current limiting comparator input.
PGOUT	18	0	Open drain output for power good signal
PG_DELAY	19	I/O	Programmable delay for power good. Connect to the external capacitor for timer delay.
PHASE_12V	23	I	Phase compensation for the 12-V boost converter. Connect to an external capacitor. But normally it is not connected.
PWM_SEL	7	I	PWM or auto PWM/SKIP modes select L: PWM fixed H: auto PWM/SKIP
REF	10	0	1.185 V reference voltage output



#### **Terminal Functions(Continued)**

TERMINAL		1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
REG5V_IN	42	I	External 5 V input
SCP	17	I/O	Short circuit protection terminal. An external capacitor is connected between SCP and GND to set the SCP enable time up.
SOFTSTART1	2	I/O	External capacitor from SOFTSTART1 to GND for CH1 soft starts control.
SOFTSTART2	6	I/O	External capacitor from SOFTSTART2 to GND for CH2 soft starts control.
SOFTSTART3	24	I/O	External capacitor from SOFTSTART3 to GND for CH3 soft starts control.
SOFTSTART_12V	22	I/O	External capacitor from SOFTSTART_12V to GND for CH4 (12-V boost converter) soft starts control.
STBY1	13	I	Stand by control for CH1
STBY2	14	- 1	Stand by control for CH2
STBY3	16	1	Stand by control for CH3
STBY12V	15	1	Stand by control for 12-V boost converter
STBY_VREF3.3	11	1	Stand by control for 3.3-V linear regulator
STBY_VREF5	12	Ι	Stand by control for 5-V linear regulator
TRIP1	55	I	External resistor connection for CH1 output current protection control
TRIP2	53	Ι	External resistor connection for CH2 output current protection control
TRIP3	34	Ι	External resistor connection for CH3 output current protection control
VCC	46		Supply voltage input
V <sub>CC</sub> _SENSE12	54	I	Supply voltage input and input voltage terminal for CH1/2 output current sense
V <sub>CC</sub> _SENSE3	35	I	Supply voltage input and input voltage terminal for CH3 output current sense
VREF3.3	44	0	3.3-V linear regulator output
VREF5	43	0	5-V linear regulator output

#### detailed description

#### **REF (1.185 V)**

The reference voltage is used for setting the output voltage and voltage protection. This reference voltage is dropped down from the 5-V regulator. The tolerance is 1.5 % over the entire temperature range.

#### CH1, 2, 3 (synchronous buck controller)

The TPS5140 includes three synchronous buck controllers. CH2 and CH3 (5 V and 2.5 V) are operated in phase, but CH1 (3.3 V) is operated 180° out of phase from CH2 and CH3, but at the same frequency. All channels have separate standby and softstart control.

#### 12-V boost converter

OUT\_12V is a 12-V boost converter output . It can isolate  $V_I$  (5 V) and  $V_O$  fully.

#### 5-V regulator

An internal linear voltage regulator is used for the high-side driver bootstrap voltage and as the source of  $V_{ref}$ . When the 5-V regulator is disconnected from the MOSFET drivers, it is used only for the source of  $V_{ref}$ . Since the input voltage is from 4.5 V to 28 V, this feature offers a fixed bootstrap voltage to simplify the drive design. The 5-V regulator is also used for powering the low side driver. The 5-V regulator is active if STBY\_VREF5 is high and has a tolerance of 4%.



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#### detailed description (continued)

#### 3.3-V regulator

TPS5140 has a 3.3-V linear regulator. The output is made from the internal 5 V regulator or external 5 V from REG5V\_IN. The 3.3-V regulator has an output current limit. The maximum output current is 30 mA.

#### 5-V switch

If the internal 5-V switch senses a 5-V input from the REG5V\_IN terminal, the internal 5-V linear regulator will be disconnected from the MOSFET drivers. The external 5 V will be used for both the low-side driver and the high-side bootstrap, thus increasing the efficiency.

#### auto PWM/SKIP

The PWM\_SEL terminal selects either the auto PWM/SKIP or fixed PWM mode. If this terminal is lower than 0.5 V, the outputs operate in the fixed PWM mode. If 2.5 V (minimum) is applied, the outputs operate in auto PWM/SKIP mode. In the auto PWM/SKIP mode, the operation changes from the PWM mode to the SKIP mode automatically under light load conditions. Avoid using a MOSFET with very low  $r_{DS(on)}$  if the auto SKIP function is implemented.

#### error amp

All three synchronous buck channels have their own error amplifier to regulate the output. The error amplifier is used in the PWM mode for high output current conditions (> 0.2 A). Voltage mode control is implemented.

#### skip comparator

In skip mode, all three synchronous buck channels have their own hysteresis comparator to regulate the output voltages. The hysteresis voltage is set internally and typically at 8.5 mV. The delay from the comparator input to the driver output is typically  $1.2 \, \mu s$ .

#### low-side driver

The low-side driver is designed to drive low- $r_{DS(on)}$  n-channel MOSFETs. The maximum drive voltage is 5 V from VREF5. Ch1, 2, and 3 MOSFET driver capability is 1.5 A, source and sink.

#### high-side driver

The high-side driver is designed to drive low-r<sub>DS(on)</sub> n-channel MOSFETs. CH1 and CH2 MOSFET drivers have 1.2 A capability, source and sink. When configured as a floating driver, the bias voltage to the driver is developed from VREF5, limiting the maximum drive voltage between OUT\_u and LL to 5 V. The maximum voltage that can be applied between LHx and OUTGND is 33 V.

#### dead time

Dead time prevents shoot-through current from flowing through the main power MOSFETs during switching transitions by actively controlling the turnon time of the MOSFETs drivers.

#### current protection

Current protection is achieved by sensing the drain-to-source voltage drop of the low-side power MOSFET during the low-side MOSFET's on time at OUTGND and LL. An external resistor between  $V_{CC_-}$  SENSE and TRIP terminal in series with the internal current source adjusts the current limit. When the voltage drop during the low-side MOSFET on-time is high enough, the current comparator triggers the current protection and the MOSFET drivers are turned off. After a programmable time delay, the SCP circuit latches off all MOSFET drivers. The internal current source tolerance is  $\pm 10\%$ . CH2 monitors both high-side and low-side MOSFET voltage drops.



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#### detailed description (continued)

#### **OVP**

For over voltage protection, the TPS5140 monitors INV terminal voltage. When the INV voltage becomes higher than 1.185 V (+12%), the OVP comparator output becomes high and the SCP timer starts to charge the SCP capacitor. After a programmable time delay, the SCP circuit forces CH1, 2, 3 high-side MOSFET drivers to latch off and the low-side MOSFET drivers to latch on.

#### **UVP**

For under voltage protection, the TPS5140 monitors INV terminal voltage. When the INV voltage becomes lower than 1.185 V (–18 %), the UVP comparator output becomes high and the SCP timer starts to charge the SCP capacitor. Also, when the current comparator of CH1, 2, 3 triggers the OCP, the UVP comparator detects the under voltage output and the SCP capacitor starts to charge. After the programmable time delay, the SCP circuit forces the CH1, 2, 3 MOSFET drivers to latch off.

#### **SCP**

When an OVP or UVP comparator output becomes high, the SCP circuit starts to charge the SCP capacitor. The charging source current value is different between OVP alert and UVP alert.

SCP source current (OVP) = SCP source current (UVP)  $\times$  5

The threshold voltage of SCP comparator is 1.185 V.

#### power good

The power good output reports the output fail condition. PG comparators monitor an under voltage or over voltage of CH1, 2, 3, with a threshold of –7 % and 7 %. TPS5140 has an EXT\_PG terminal, which can be used for the input of an external PG signal. Delay time is programmable by charging an external capacitor on the PG DELAY terminal.

### SOFTSTART1, 2, 3

Separate soft start terminals make it possible to customize the start-up time of each output. The voltage on the charging softstart capacitor gradually raises, limiting the surge current and voltage. A soft start is initiated when the STBY terminals are switched.

#### STBY1, 2, 3, 12V

CH1, 2, 3 and 12V can be switched into standby mode separately by grounding the STBY terminal.

#### STBY VREF3.3, 5V

STBY\_VREF3.3 shuts down the 3.3-V regulator by grounding the STBY\_VREF3.3 terminal. When STBY\_VREF5 is high, only the 5-V regulator is operating.

#### **UVLO**

When the input voltage exceeds 4 V, the IC is turned on and is ready to function. When the input voltage is lower than the turn on value, the IC is turned off. The typical hysteresis voltage is 40 mV.

#### phase inverter

The phase inverter controls the phase of CH1 and CH2, 3. CH2, 3 operate in the same phase as OSC. CH1 operates 180° out of phase from OSC. Out-of-phase operation enables a smaller input capacitor.

#### **OVP (12-V boost converter)**

The TPS5140 monitors over voltage of the 12-V boost converter. When an output over voltage is detected, the timer starts to charge an external capacitor that is connected to the SCP terminal. After a programmable time delay, the SCP circuit forces all (CH1, 2, 3 and 12 V) MOSFET drivers to latch-off.



#### detailed description (continued)

#### **UVP (12-V boost converter)**

TPS5140 monitors output under voltage of the 12-V boost converter. When an output under voltage is detected, the timer starts to charge an external capacitor that is connected to the SCP terminal. After a programmable time delay, the SCP circuit forces all (CH1, 2, 3, and 12 V) MOSFETs drivers to latch off.

#### SOFTSTART 12V

An internal capacitor exists for 12-V soft start. If the soft start time needs to be extended, an external capacitor should be connected to this terminal. The 12-V boost converter must start when REG5V\_IN terminal is over 4.5 V.

#### current limit of 12-V boost converter

The 12-V boost current limit monitors the current flowing through the internal MOSFET. When the voltage drop across the internal N-channel MOSFET is high enough during its on time, the current limit circuit forces the internal N-channel MOSFET to turn off.

#### PHASE 12V

The 12-V boost converter does not typically require phase compensation. If there is reason to change the phase, the 12-V boost converter can be phase compensated by inserting external resistors and capacitors to GND. Otherwise, the PHASE\_12V terminal should be left open.

#### logic charts

Table 1. Logic Chart1

STBY1	STBY2	STBY3	CH1	CH2	СНЗ	PGOUT
L	L	L	Disable	Disable	Disable	N/A
L	L	Н	Disable	Disable	Enable	Active <sup>†</sup>
L	Н	L	Disable	Enable	Disable	Active†
L	Н	Н	Disable	Enable	Enable	Active†
Н	L	L	Enable	Disable	Disable	Active†
Н	L	Н	Enable	Disable	Enable	Active†
Н	Н	L	Enable	Enable	Disable	Active <sup>†</sup>
Н	Н	Н	Enable	Enable	Enable	Active <sup>†</sup>

<sup>†</sup> During softstart, PGOUT is active low.

**Table 2. Logic Chart2** 

STBY_VREF5	STBY_VREF3.3	VREF5‡	VREF3.3
L	L	N/A	Disable
Н	L	Enable	Disable
L	Н	Enable	Enable
Н	Н	Enable	Enable

<sup>&</sup>lt;sup>‡</sup>To disable VREF5, all STBY1, 2, 3, STBY\_VREF3.3 and STBY\_VREF5 must be L.

**Table 3. Logic Chart3** 

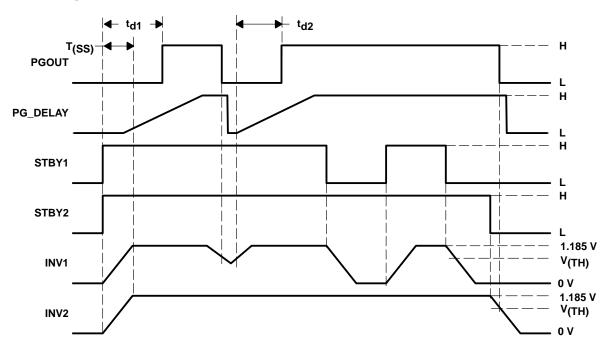
STBY12V	REG5V_IN	12 VOUT
L	L	Disable
L	Н	Disable
Н	L	Disable
Н	Н	Enable



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# **PGOUT timing chart**



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#### absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1) –	-0.3 V to 30 V
Input voltage; INV1/2/3, CT, PWM_SEL, REG5V_IN, SOFTSTART1/2/3, SOFTSTART_12V	-0.3~V to $7~V$
SCP, PG_DELAY, PHASE_12V, OUT1/2/3_d, VREF3.3/5, FB1/2/3	-0.3~V to $7~V$
PGOUT, EXT_PG	-0.3~V to $7~V$
STBY1/2/3/12V, STBY_VREF3.3/5, TRIP1/2/3 –	-0.3 V to 30 V
VCC_SENSE12/3, LL1/2/3 –	-0.3 V to 30 V
LL_UP, OUT_12V, IN_12V –	-0.3 V to 16 V
LH1/2/3, OUT1/2/3_u –	-0.3 V to 35 V
REF	-0.3  V to 3 V
Operating free-air temperature range, T <sub>A</sub> (see Note 3) –2	20°C to 85°C
Storage temperature range, T <sub>stg</sub>	5°C to 155°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to the network ground terminal.

- 2. This rating is specified at duty = 10% on output rise and fall each pulse. Each pulse width (rise and fall) for the peak current should not exceed 2 μs.
- 3. See Dissipation Rating Table for free-air temperature range above 25°C.

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ Power dissipation	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 85°C POWER DISSIPATION
PAG	1811 mW	14.49 mW/°C	941.6 mW

#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>		4.5		28	V
	INV1/2/3, CT, PG_DELAY, PWM_SEL SOFTSTART1/2/3 SOFT- START_12V, SCP PHASE_12V, PGOUT, EXT_PG,			6	
Input voltage, V <sub>I</sub>	REG5V_IN	-0.1		5.5	.,
	STBY1/2/3/12V STBY_VREF3.3/5, TRIP1/2/3, V <sub>CC</sub> _SENSE12/3	-0.1		28	V
	OUT1/2/3_u, LH1/2/3	-0.1		33	
	LL_UP, OUT_12V, IN_12V	-0.1		15	
Oscillator frequency, fosc	CT capacitance <sup>‡</sup>	44		, and the second	pF
Operation temperature range	ge, T <sub>A</sub>	-20		85	°C

<sup>&</sup>lt;sup>‡</sup> The recommended maximum operating frequency is typically 300 kHz.

# electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 7 \text{ V}$ (unless otherwise noted)

#### reference voltage

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference voltage			1.185		V
V 44 11	Peteronee voltage teleronee	$T_A = 25^{\circ}C$ , $I_{(vref)} = 50 \mu A$	-1%		1%	
Vref(tol)	Reference voltage tolerance	I <sub>(vref)</sub> = 50 μA	-1.5%		1.5%	
	Line regulation	$V_{CC} = 4.5 \text{ V to } 28 \text{ V},  I_{(vref)} = 50 \mu\text{A}$		0.05	3	mV
	Load regulation	I <sub>(vref)</sub> = 0.1 μA to 1 mA		0.15	5	mV



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electrical characteristics over recommended operating free-air temperature range,  $V_{CC} = 7 \text{ V}$  (unless otherwise noted) (continued)

#### oscillator

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
fosc	Frequency	PWM mode, CT = 56 pF, T <sub>A</sub> = 25°C		250		kHz
V	High level output voltage	DC	1	1.1	1.2	V
VOS(CH)	High-level output voltage	f <sub>OSC</sub> = 250 kHz		1.17		V
V	Low level cutout valtage	DC	0.4	0.5	0.6	V
VOS(CL)	Low-level output voltage	f <sub>OSC</sub> = 250 kHz		0.43		V

## error amplifier

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IO</sub>	Input offset voltage	T <sub>A</sub> = 25°C		2	10	mV
A <sub>(V)</sub>	Open-loop voltage gain			90		dB
G <sub>(B)</sub>	Unity-gain bandwidth			2.5		MHz
I <sub>(snk)</sub>	Output sink current	Vo = 1 V	0.3	0.7		m A
I <sub>(src)</sub>	Output source current	V <sub>O</sub> = 1 V	0.4	0.9		mA

#### duty control

PARAMETER	TEST CONDITIONS	MAX	UNIT		
	CH1/3, f <sub>OSC</sub> = 250 kHz	75%			
Maximum duty cycle	CH2, f <sub>OSC</sub> = 250 kHz	85%			
	12V boost, f <sub>OSC</sub> = 250 kHz		70%		

#### control

	PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT
VIH	High-level input voltage	STBY1/2/3/12V, EXT_PGPWM_SEL, STBY_VREF5/3.3	2			V
VIL	Low-level input voltage	STBY1/2/3/12V, EXT_PGPWM_SEL, STBY_VREF5/3.3			0.3	V

#### 5-V internal switch

PARAMETER		TEST CONDITIONS	MIN	TYP MAX	UNIT	
V <sub>(TLH)</sub>	Threshold voltage	High	REG5V_IN	4.2	4.8	. ,
V <sub>(THL)</sub>	Threshold voltage	Low	REG5V_IN	4.1	4.7	<b>]</b>
$V_{hys}$	Hysteresis			30	200	mV

#### VREF5

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
۷o	Output voltage		$I_O = 0$ mA to 50 mA, $T_A = 25^{\circ}C$	$V_{CC} = 5.5 \text{ V to } 28 \text{ V},$	4.8		5.2	V
	Line regulation		$V_{CC} = 5.5 \text{ V to } 28 \text{ V},$	I <sub>O</sub> = 10 mA			20	mV
	Load regulation		$I_O = 1 \text{ mA to } 10 \text{ mA},$	V <sub>CC</sub> = 5.5 V			40	mV
los	Short circuit output current		$V_{ref} = 0 V$ ,	T <sub>A</sub> = 25°C	65			mA
V(TLH)	LIVI O throubold voltage	High	VREF5 voltage		3.6		4.2	V
V <sub>(THL)</sub>	UVLO threshold voltage	Low	VKEF5 voltage		3.5		4.1	V
$V_{hys}$	Hysteresis		VREF5 voltage		30		200	mV



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# electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 7 \text{ V}$ (unless otherwise noted) (continued)

#### VREF3.3

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT
۷o	Output voltage	$I_O = 0$ mA to 30 mA, $T_A = 25$ °C	$V_{CC} = 5.5 \text{ V to } 28 \text{ V},$	3.15	3.30	3.45	V
	Line regulation	$V_{CC} = 5.5 \text{ V to } 28 \text{ V},$	I <sub>O</sub> = 10 mA			20	mV
	Load regulation	$I_O = 1 \text{ mA to } 10 \text{ mA},$	V <sub>CC</sub> = 5.5 V			40	mV
los	Short circuit output current	$V_{ref} = 0 V$ ,	T <sub>A</sub> = 25°C	-40			mA

#### output

	PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
OUT u	Sink current	V <sub>O</sub> = 3 V			1.2		Α
001_u	Source current	V <sub>O</sub> = 2 V			-1.2		ť
OUT d	Sink current	V <sub>O</sub> = 3 V			1.5		Α
001_u	Source current	V <sub>O</sub> = 2 V			-1.5		ť
LL_UP	Sink current	$V_{LL\_UP} = 0.3 V$ ,	OUT_12V = 12 V		0.65		Α
OUT_12V	Output impedance	IN_12V = 12 V,	I <sub>OUT_12V</sub> = 150 mA		1.1		Ω
I(TRIP)	TRIP current	TRIP1/2/3,	T <sub>A</sub> = 25°C	11.5	13	15	μΑ

#### softstart

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
l. 6.6.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.4.	Softstart1/2/3	-1.6	-2.3	-2.9	
I(CTRL) Soft start current	Softstart_12V		-0.007		μΑ

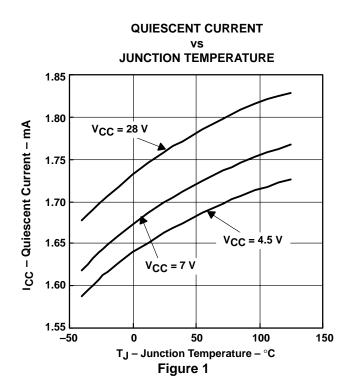
#### output voltage monitor

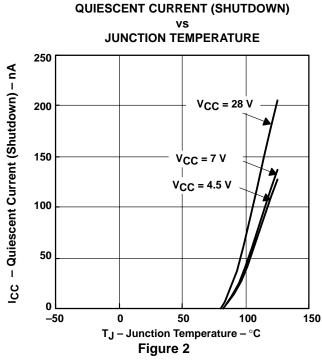
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	OVP comparator threshold voltage	CH1/2/3	1.28	1.33	1.38	V
	OVP comparator threshold voltage	12 V boost	12.9	13.4	13.9	V
	UVP comparator threshold voltage	CH1/2/3	0.90	0.95	1	V
	OVF comparator trieshold voltage	12 V boost	9	9.5	10	V
	PG comparator threshold voltage	PG comparator1/2/3, upper threshold	1.22	1.27	1.32	V
	ro comparator trireshold voltage	PG comparator1/2/3, lower threshold	1.05	1.1	1.15	V
	PG propagation delay from INV to	INV = 0.985 V to 1.185 V, PG_DELAY = open		3.7		
	PG_OÚT	INV = 1.185 V to 0.985 V, PG_DELAY = open		8.9		μs
IPG_DELAY)	PG_DELAY source current		1.1	1.7	2.3	μΑ
lana.	CCD course oursest	UVP protection	1.5	2.3	3.1	
I(SCP)	SCP source current	OVP protection	8	11.5	15	μΑ

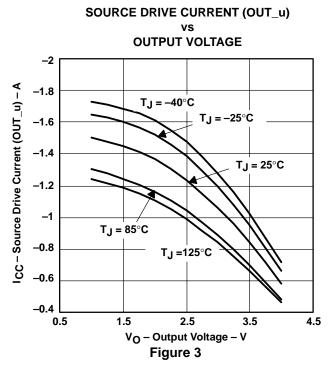
#### whole device

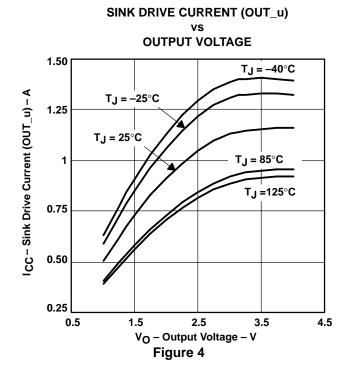
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ICC	Supply current			1.8	2.6	mA
IO(SD)	Shutdown current	STBY1/2/3/12V, STBY_VREF5/3.3 = 0 V		0.001	10	μΑ

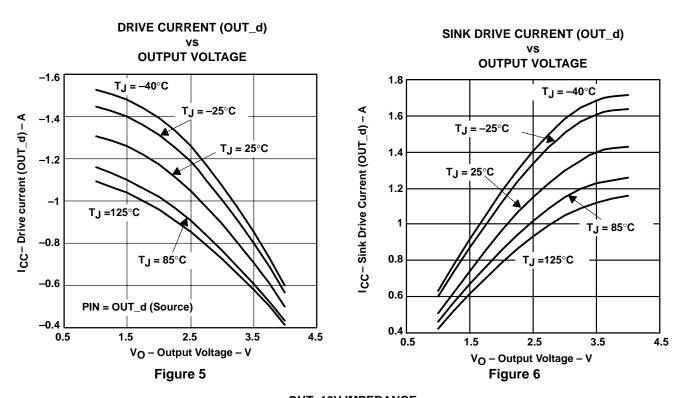


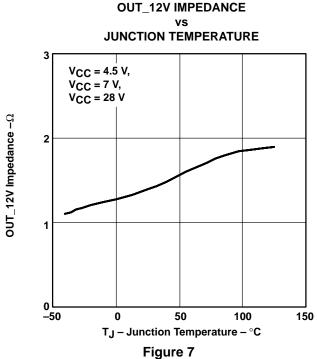


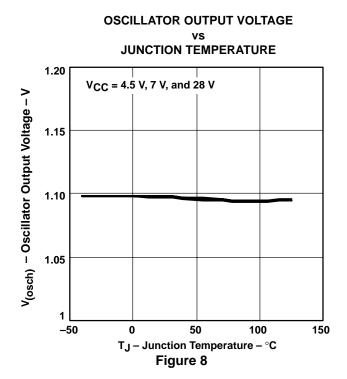


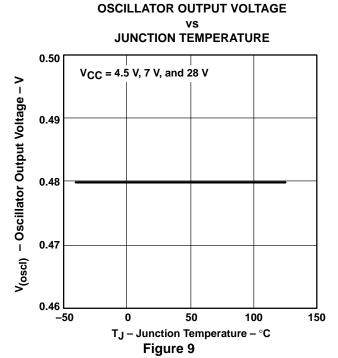












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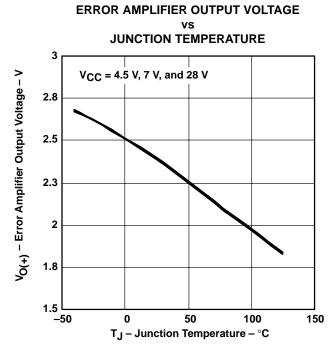
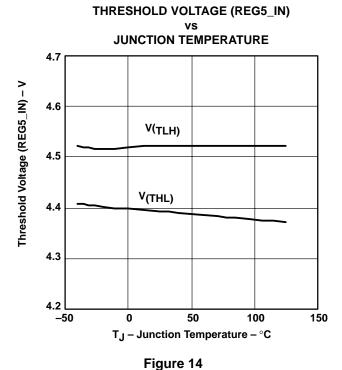


Figure 11

# 

Figure 12



STANDBY SWITCH THRESHOLD VOLTAGE

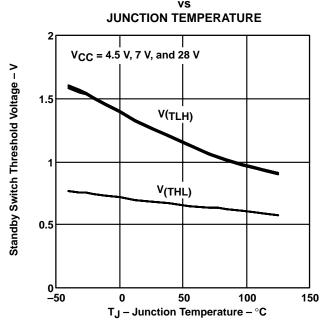


Figure 13

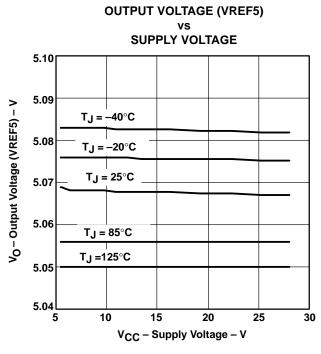


Figure 15

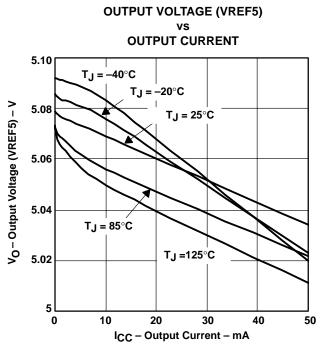


Figure 16

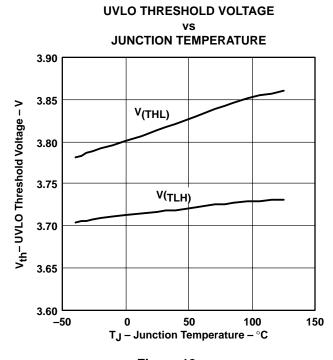


Figure 18

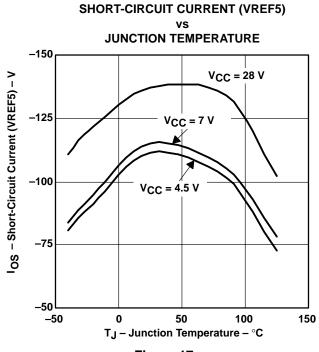


Figure 17

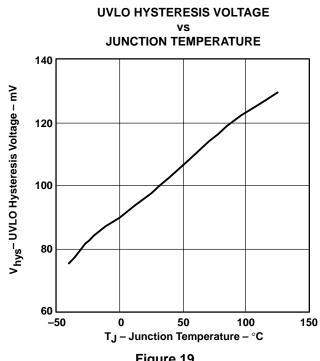


Figure 19

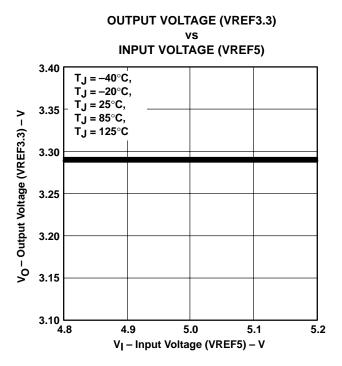


Figure 20

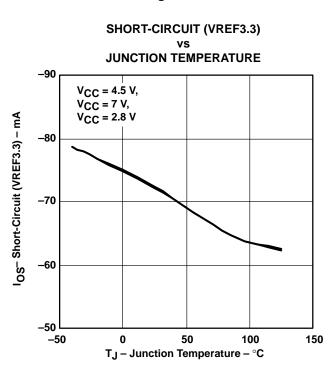


Figure 22

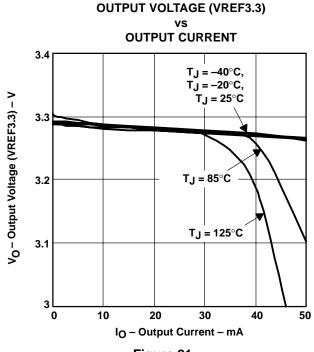


Figure 21

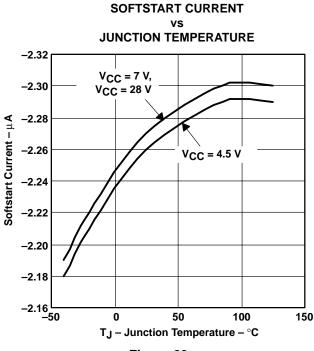


Figure 23

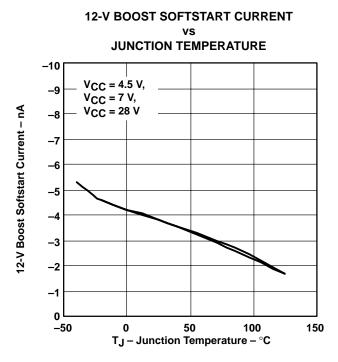


Figure 24

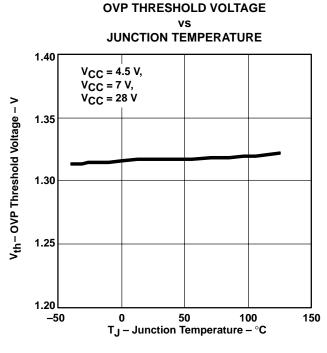
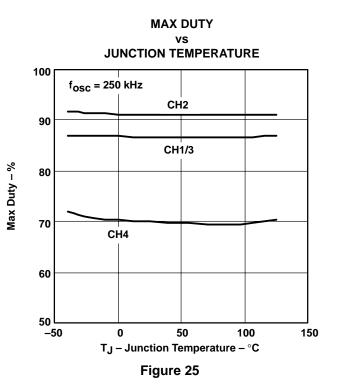


Figure 26



12-V BOOST OVP THRESHOLD VOLTAGE
vs
JUNCTION TEMPERATURE

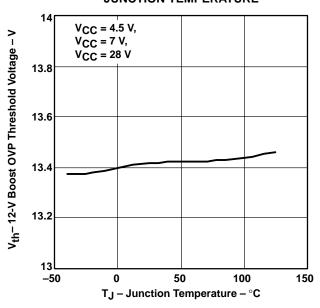


Figure 27

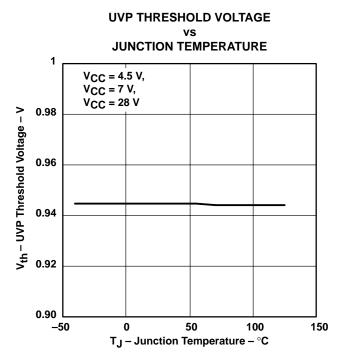


Figure 28

## POWER GOOD THRESHOLD VOLTAGE vs **JUNCTION TEMPERATURE** 1.30 V<sub>th</sub> - Power Good Threshold Voltage - V 1.25 V(TLH) 1.20 $V_{CC} = 4.5 V$ $V_{CC} = 7 V$ V<sub>CC</sub> = 28 V 1.15 V<sub>(THL)</sub> 1.10 1.05 -50 50 100 150 T<sub>J</sub> - Junction Temperature - °C

Figure 30

# 12-V BOOST UVP THRESHOLD VOLTAGE vs JUNCTION TEMPERATURE

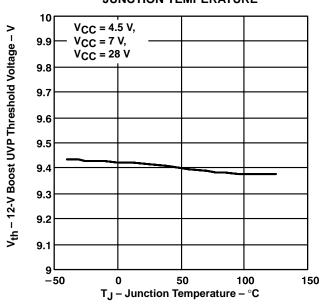


Figure 29

# THRESHOLD VOLTAGE (EXT\_PG) vs

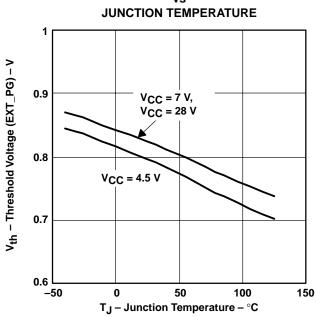
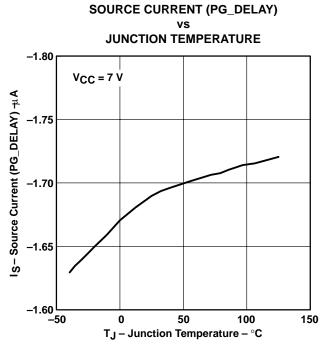
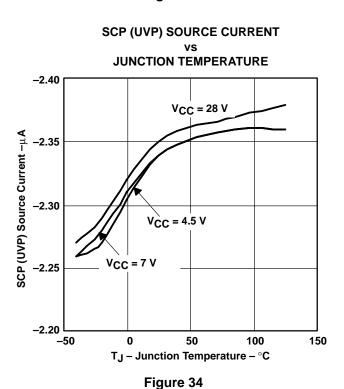


Figure 31







SCP (OVP) SOURCE CURRENT vs

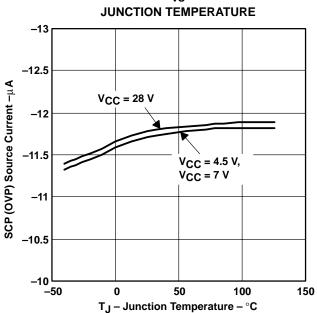


Figure 33

## TRIP SINK CURRENT vs TRIP INPUT VOLTAGE

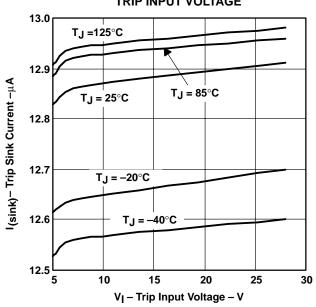


Figure 35

**OSCILLATOR OUTPUT VOLTAGE** 

**FREQUENCY** 

VO(SCH)

#### **TYPICAL CHARACTERISTICS**

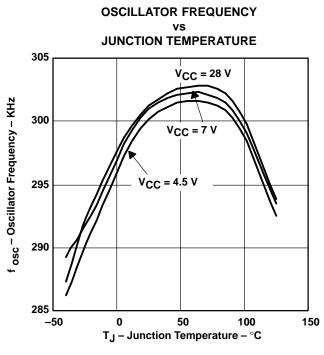


Figure 36

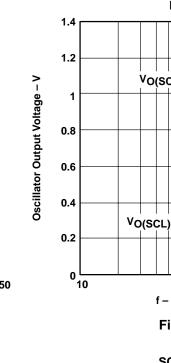


Figure 37

100

f - Frequency - KHz

1000

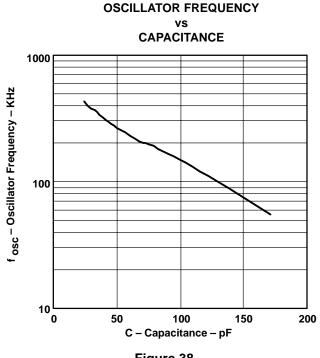


Figure 38

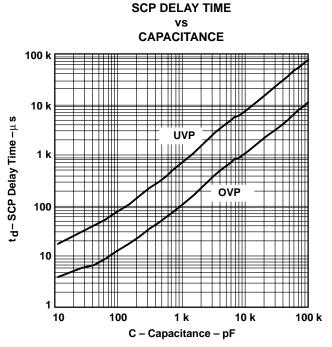
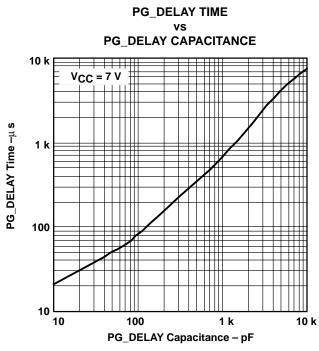
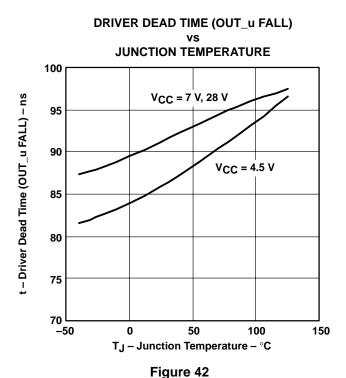


Figure 39

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265







SOFTSTART TIME vs

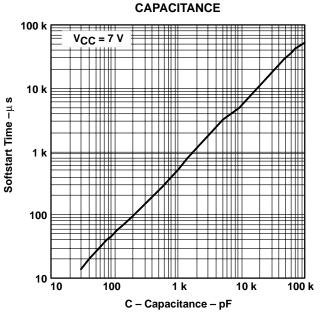


Figure 41

# DRIVER DEAD TIME (OUT\_u RISE) vs

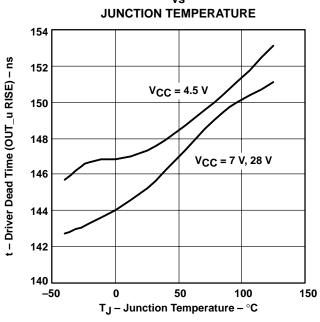


Figure 43

# TPS5140 FOUR-CHANNEL DC/DC CONTROLLER FOR NOTEBOOK PC POWER

SLVS305A - DECEMBER 2000 - REVISED JANUARY 2001

#### **APPLICATION INFORMATION**

The design shown in this data sheet is a reference design for system power of notebook PC applications. An evaluation module (EVM), TPS5140EVM-172 (SLVP172), is available for customer testing and evaluation. The intent is to allow a customer to fully evaluate the given design using the plug-in EVM supply shown here. For subsequent customer board revisions, the EVM design can be copied onto the users' PCB to shorten design cycle. The following key design procedures will aid in the design of the notebook PC power supply using the TPS5140.

#### **EVM** input and outputs

		V <sub>O</sub> 1	V <sub>O</sub> 2	V <sub>O</sub> 3	V <sub>O</sub> 4
Output voltage	V <sub>I</sub> range = 7 V ≈ 25 V	3.3 V	5 V	2.5 V	12 V
Maximum output current	$I_{I(max)} = 9 A$	4 A	5 A	2 A	120 mA

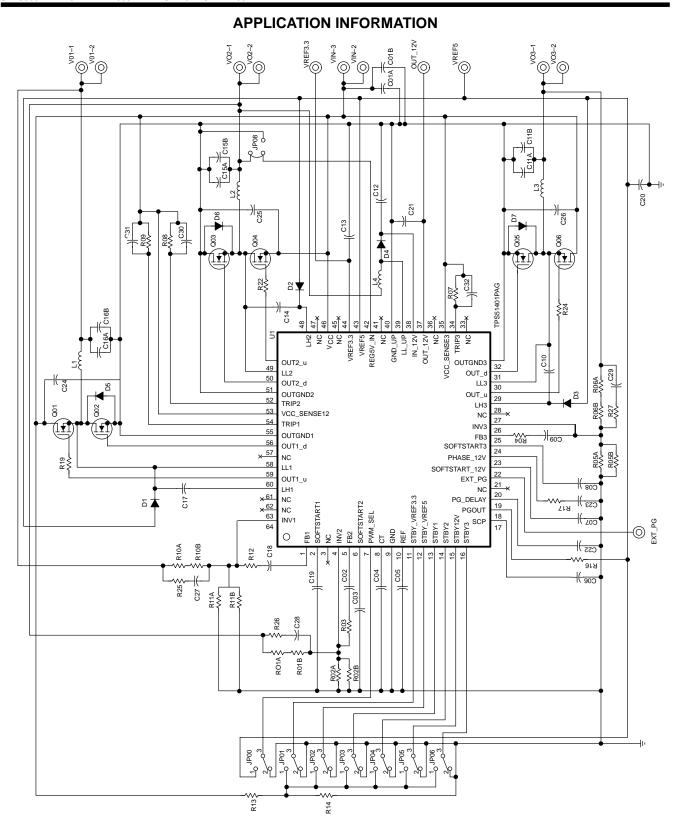


Figure 44. EVM Schematic



#### SMPS (synchronous mode power supply)

#### output voltage setpoint calculation

The reference voltage and the voltage divider set the output voltage. In the TPS5140, the reference voltage is 1.185 V, and the divider is composed of two resistors in the EVM design that are R01A, R01B and R02A, R02B, or R10A, R10B and R11A, R11B, or R06A, R06B and R05A, R05B. The equation for the setpoint is:

$$R1 = \frac{R2 \times \left(V_{O} - V_{ref}\right)}{V_{ref}}$$

where R1 is the top resistor ( $k\Omega$ ) (R01A and R01B, R10A and R10B or R06A and R06B); R2 is the bottom resistor ( $k\Omega$ ) (R02A and R02B, R11A and R11B or R05A and R05B);  $V_O$  is the required output voltage (V);  $V_{ref}$  is the reference voltage (1.185 V in TPS5140).

Example: R2 = 10 k $\Omega$ ; V<sub>ref</sub> = 1.185 V; V<sub>O</sub> = 5 V, then R1 = 32.19 k $\Omega$ 

Some of the most popular output voltage setpoints are calculated in the table below:

v <sub>o</sub>	1.3 V	1.5 V	1.8 V	2.5 V	3.3 V	5 V
R1 (top) (kΩ)	0.97	2.66	5.19	11.10	17.85	32.19
R2 (bottom) (k $\Omega$ )	10	10	10	10	10	10

If user changes the resistor value, the R2 (bottom) value should be over 10 k $\Omega$  due to the phase compensation.

#### output inductor ripple current

The output inductor current I<sub>(ripple)</sub> can affect not only the efficiency, but also the output voltage ripple. The equation is exhibited below:

$$I_{(ripple)} = \frac{V_{I} - V_{O} - I_{O} \times \left(r_{DS(on)} + R_{L}\right)}{L_{(out)}} \times D \times t_{S}$$

where ripple is the peak-to-peak ripple current (A) through the inductor;  $V_I$  is the input voltage (V);  $V_O$  is the output voltage (V);  $V_O$  is the output current;  $v_D v_D v_D$  is the on-time resistance of the MOSFET ( $v_D v_D v_D$ );  $v_D v_D v_D$  is the on-time resistance of the MOSFET ( $v_D v_D v_D v_D$ );  $v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor;  $v_D v_D v_D v_D v_D v_D v_D v_D v_D$  is the output of the inductor of the ind

Example: If  $V_I$  = 10 V;  $V_O$  = 5 V;  $I_O$  = 5 A;  $r_{DS(on)}$  = 26 m $\Omega$ ;  $R_L$  = 5 m $\Omega$ ; D = 0.50;  $t_S$  = 4  $\mu$ s;  $L_{(out)}$  = 6.1  $\mu$ H, then the ripple current  $I_{(ripple)}$  = 1.589 A.

#### output capacitor RMS current

Assuming the inductor ripple current goes completely through the output capacitor to ground, the RMS current in the output capacitor can be calculated as:

$$I_{O(rms)} = I_{(ripple)} \times \frac{\sqrt{3}}{6}$$

where  $I_{O(rms)}$  is the maximum RMS current in the output capacitor (A) and  $I_{(ripple)}$  is the peak-to-peak inductor ripple current (A).

Example:  $I_{(ripple)} = 1.589 \text{ A}$ , so  $I_{O(rms)} = 0.459 \text{ A}$ 



#### SMPS (synchronous mode power supply) (continued)

#### input capacitor RMS current

Assuming the input current goes completely into the input capacitor to the power ground, the RMS current in the input capacitor can be calculated as:

$$I_{l(rms)} = \sqrt{I_0^2 \times D \times (1-D)}$$

where I<sub>I(rms)</sub> is the input RMS current in the input capacitor (A), I<sub>O</sub> is the output current (A), and D is the duty cycle. From the equation, it can be seen that the highest input RMS current usually occurs at the lowest input voltage, so it is the worst case design for input capacitor ripple current.

Example:  $I_0 = 5 A$ ; D = 0.50

Then,  $I_{I(rms)} = 2.5 A$ .

#### soft start

The soft start timing can be adjusted by selecting the soft start capacitor value. The equation is exhibited below:

$$C(soft) = \frac{2.3 \times T(soft)}{1.185}$$

where C(soft) is the soft start capacitor ( $\mu$ F) (C19, C03 or C08 in EVM design), and T(soft) is the start up time (s).

Example: T(soft) = 5 ms, so  $C(soft) = 0.01 \mu F$ .

#### current limit protection

The current limit in the TPS5140 on each channel is set using an internal current source and an external resistor (R09, R08 or R07). The sensed low-side MOSFET drain-to-source voltage is compared to the set point. If the voltage exceeds the limit, the internal oscillator is activated, and it continuously resets the current limit until the over-current condition is removed or SCP latches outputs off (see timer-latch SCP). The equation below should be used for calculating the external resistor value for the current protection set point. Also, only CH2 monitors both high-side and low-side MOSFET drain-to-source voltage.

$$R(cl) = \frac{r_{DS(on)} \times \left(I_{(trip)} + \frac{I_{(ripple)}}{2}\right)}{0.000013}$$

where  $R_{(cl)}$  is the external current limit resistor (R09, R08 or R07), and  $r_{DS(on)}$  is the low side MOSFET (Q02, Q03 or Q05) on-time resistance.  $I_{(trip)}$  is the required current limit and  $I_{(ripple)}$  is the peak-to-peak output inductor current.

Example:  $r_{DS(on)} = 26 \text{ m}\Omega$ , I(trip) = 7 A,  $I_{(ripple)} = 1.589 \text{ A}$ , so  $R_{(cl)} = 16 \text{ k}\Omega$ .



#### SMPS (synchronous mode power supply) (continued)

#### timer-latch SCP

The TPS5140 includes the function of the fault latch with timer to latch the MOSFET driver after constant time passes since the unusual condition of the output was detected. When the OVP or UVP comparator detects a fault condition, the timer starts to charge the SCP capacitor (C06), which is connected to the SCP terminal. If the SCP terminal goes up to 1.185 V, the fault latch is set.

#### over current protection and under voltage protection

When the current limit circuit limits the output current, then the output voltage will go below the target output voltage and the UVP comparator detects a fault condition. The timer starts to charge the SCP capacitor when the UVP comparator detects the output under voltage and the fault latch will be set after  $T_{(uvplatch)}$  has past. When UVP is latched, all output MOSFET drivers of the TPS5140 turn *OFF*. The equation below should be used for calculating the  $T_{(uvplatch)}$ :

$$C_{\text{(scp)}} = \frac{2.3 \times T_{\text{(uvplatch)}}}{1.185}$$

#### over voltage protection

When OVP comparator detects the output over voltage, the timer starts to charge the SCP capacitor, and the fault latch will be set after  $T_{(ovplatch)}$  has past. In case of OVP-latch, the high-side drivers of both channels are forced OFF and the low-side drivers of both channels are forced ON. The equation below should be used for calculating the  $T_{(ovplatch)}$ :

$$C_{\text{(scp)}} = \frac{11.5 \times T_{\text{(ovplatch)}}}{1.185}$$

where  $C_{(scp)}$  is the external capacitor,  $T_{(uvplatch)}$  is time from the UVP detection to latch, and  $T_{(ovplatch)}$  is the time from OVP detection to latch.

Example:  $T_{\text{(uvplatch)}} = 515 \,\mu\text{s}$ ,  $T_{\text{(ovplatch)}} = 103 \,\mu\text{s}$ , so  $C_{\text{(scp)}} = 0.001 \,\mu\text{F}$ 

#### notice—usage of timer-latch

The SCP should not be set to a lower voltage (or GND) while the device is holding the latch-off status of the OVP or UVP. If the SCP terminal is manually set to a lower voltage in this term, an output overshoot may occur. The TPS5140 must be reset by grounding the STBY1,2,3 and STBY\_VREF5,3.3 or by dropping the  $V_{CC}$  below the UVLO voltage.

#### disablement the protection function

When debugging the circuit once preliminary calculations have been performed, the evaluation may be hampered because the protection circuitry does not operate properly. In this case, the TPS5140 is able to invalidated the protection circuits for debugging.

OCP: Removing the resistor for the current limit and opening the TRIP terminal can disable the OCP. OVP, UVP: Grounding the SCP terminal can disable the OVP and UVP.



#### 3.3 V linear regulator

The VREF3.3 terminal is the output of the 3.3-V linear regulator. The VREF3.3 terminal should be connected to an output capacitor. A ceramic capacitor of 4.7  $\mu$ F is recommended for stability of the output voltage.

#### REG5V\_IN

The REG5V\_IN terminal should be connected to the external 5 V (output of CH2), to decrease the power dissipation. Also, this terminal has an OVP comparator. If this terminal voltage exceeds a threshold voltage, the timer starts to charge the SCP capacitor, and all of output is forced to *OFF*.

#### 12 V boost up converter

The TPS5140 has a boost up converter (12 V). The inductor (L4) which uses this boost up converter should be connected to the external 5 V. Also, the inductor value is recommended to be 22  $\mu$ H. The OUT\_12V terminal should be connected to the output capacitor. A ceramic capacitor of 10  $\mu$ F is recommended for stability of the output voltage. It is also recommended that a ceramic capacitor (around 0.1  $\mu$ F) be connected between the IN 12V terminal and the GND UP terminal.

#### soft start 12 V

This soft start terminal is connected to the internal capacitor. To extend the soft start time, this terminal should be connected to the external capacitor. The equation is:

$$(30 + C_{(ext)}) \times 1.185 = 3.8 \times T_{(soft\_12V)}$$

where  $C_{(ext)}$  is the 12-V soft start capacitor (pF) and  $T_{(soft-12V)}$  is the start-up time (ms).

Example: 
$$C_{(ext)} = 33 \text{ pF}$$
, so  $T_{(soft\_12V)} = 19.6 \text{ ms}$ 



#### phase compensation for 12-V boost

The 12-V boost up converter is compensated to the phase margin. If the output components are changed, the phase margin will change. Therefore, the phase margin needs to be compensated. A resistor and capacitor should be connected in series from the PHASE\_12V terminal to GND. If the inductor used is 22  $\mu$ H and the output capacitor is 10  $\mu$ F (ceramic), there is no need to compensate. The equivalent circuit of the 12-V boost is shown in Figure 45.

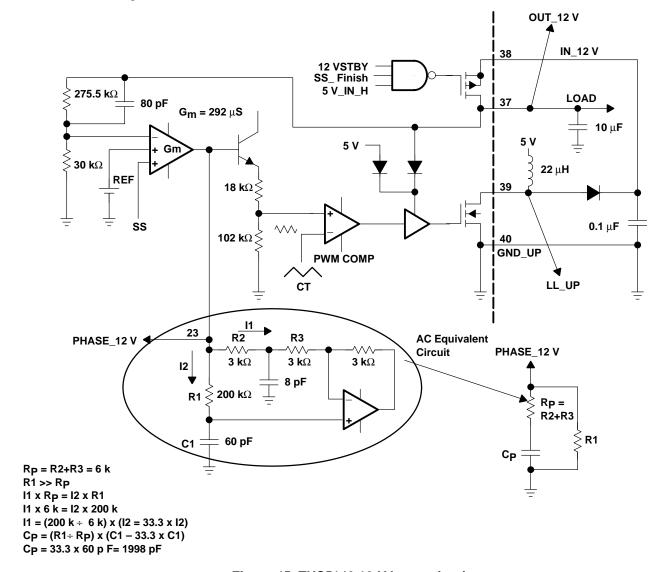


Figure 45. THS5140 12-V boost circuit

#### auto PWM/SKIP

Auto PWM/SKIP function monitors the drain-source voltage of the low-side MOSFET.

In the PWM mode to SKIP mode, when output currents decrease, the negative voltage between LL to GND is decreasing. If this voltage is positive voltage to GND, the auto SKIP circuit detects the SKIP mode. After a fixed time, the controller changes to SKIP mode.

In the SKIP mode to PMW mode, when output currents increase, the positive voltage between LL to GND is decreasing. In the SKIP mode, the auto PWM detect circuit has an offset voltage of about 20 mV. If the positive voltage between LL to GND decreases and becomes negative beyond the offset voltage of the GND level, then the auto PWM circuit detects the PWM mode, and the controller changes to the PWM mode.

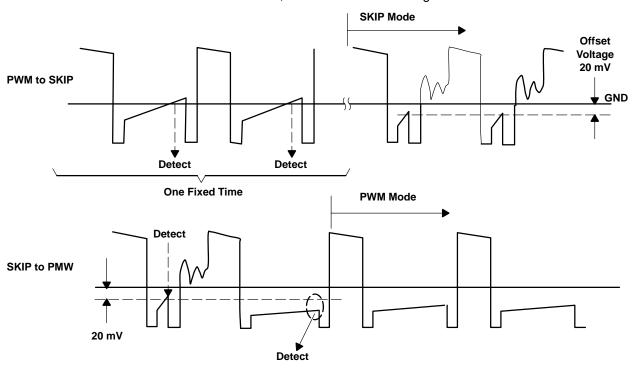


Figure 46. Timing Chart for the Auto PWM/SKIP Mode Function



#### layout guidelines

Good power supply results will only occur when care is given to proper design and layout. Layout will affect noise pickup and generation yet cause a good design to perform with less than expected results. With a range of currents from milliamps to tens of amps, good power supply layout is much more difficult than most general PCB designs. The general design should proceed from the switching node to the output, then back to the driver section and, finally, parallel the low-level components. Below are several specific points to consider before the layout of a TPS5140 design begins.

- ANAGND and DRVGND should be isolated as much as possible.
- All sensitive analog components should reference to ANAGND. Terminals INV1/2/3, REF, CT, GND, SCP, and SOFTSTART1/2/3/12V should be placed in ANAGND.
- Ideally, all of the area under TPS5140 is also ANAGND.
- The source of the low-side MOSFETs should not be placed in the trace from ANAGND to DRVGND otherwise ANAGND is under the influence of output noise.
- The switch transitions in one channel may disturb the operation of other channels. So, the impedance between V<sub>CC</sub> and GND wiring pattern should be as small as possible.
- The PCB is a four-layer pattern. This should be composed of power plane, power ground plane, signal ground plane, and signal plane.

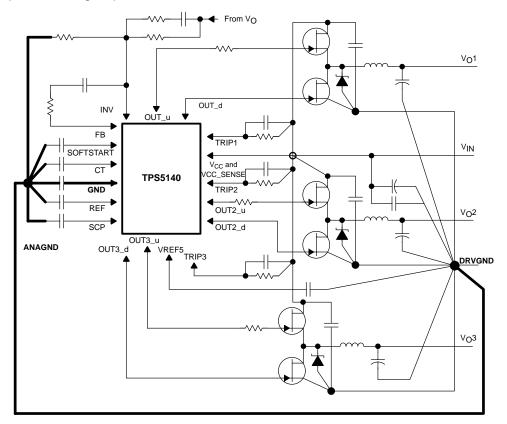


Figure 47. SLVP172 Four Layer PCB Diagram

#### layout guidelines (continued)

- DRVGND will connect to the main ground plane, close to the source of the low-side MOSFET.
- OUTGND1/2/3 should be placed close to the source of low-side MOSFET.
- The parallel Schottky diode, the high frequency bypass capacitors for MOSFETs, and the source of the low-side MOSFETs should be placed as close to each other as possible.

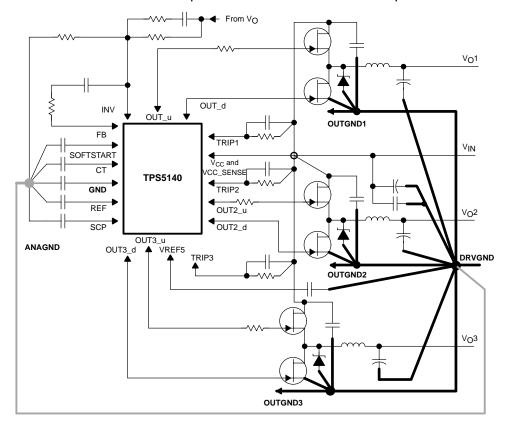


Figure 48. SLVP172 Low-Side MOSFETs Diagram

- Connections from the drivers to the gate of the power FETs should be as short and as wide as possible to
  reduce stray inductance. This becomes more critical if the external gate resistors are not being used. In
  addition, when dealing with current limit noise when using a MOSFET with a large input capacitance, a gate
  resistor should be inserted on the high side MOSFET to reduce the switching noise of the MOSFET.
- The connection from LL to the power FETs should be as short as and wide as possible.

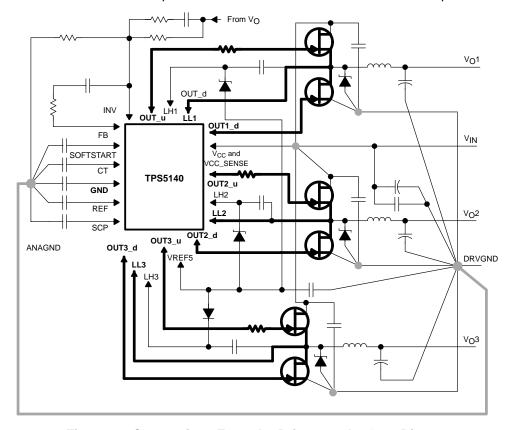


Figure 49. Connections From the Drivers to the Gate Diagram

- The bypass capacitor for V<sub>CC</sub> should be placed close to the TPS5140.
- The bulk storage capacitors across V<sub>I</sub> should be placed close to the power FETs. High-frequency bypass
  capacitors should be placed in parallel with the bulk capacitors and connected close to the drain of the
  high-side FET and to the source of the low-side FET.
- Current limit set resistors must be connected to the drain of the high-side FET. A 0.1-μF capacitor should be placed in parallel with these resistors to align the phase between the drain of high-side FETs and the trip pin.

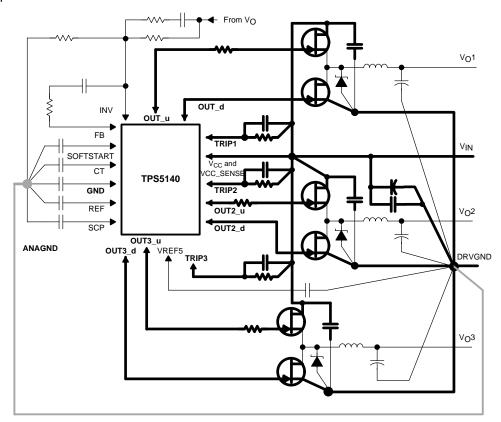


Figure 50. Bypass Capacitor Diagram



- The capacitor for VREF5 should be placed close to the TPS5140.
- The bootstrap capacitor (connected from LH to LL) should be placed close to the TPS5140.
- LH and LL should be routed close to each other to minimize differential mode noise coupling to these traces.
- The VREF5 capacitor should be placed close to DRVGND.
- LH and LL should not be routed near the control pin area. (ex. INV, FB, REF, etc.)

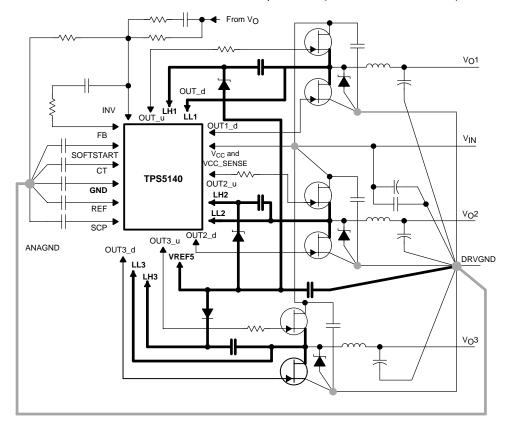


Figure 51. VREF5 Capacitor Diagram

- The output voltage sensing trace should be isolated by either ground trace.
- The output voltage sensing trace should not be routed under the inductors on same layer of the PCB.
- The feedback components should be isolated from the output components such as MOSFETs, inductors, and output capacitors. Otherwise noise from the output components may couple into the feedback signal lines.
- The resistors for the output voltage set point should be connected to ANAGND.
- INV1/2/3 line should be as short as possible.

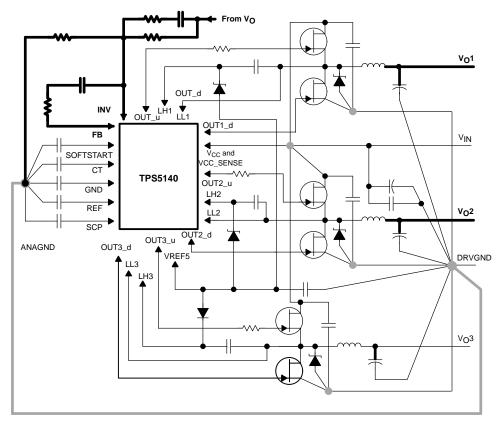


Figure 52. Output Voltage Diagram

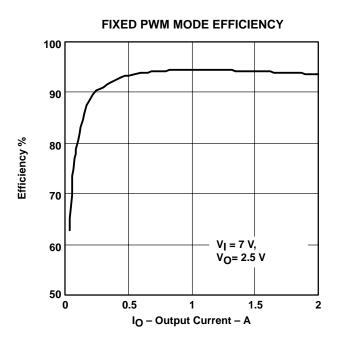


Figure 53

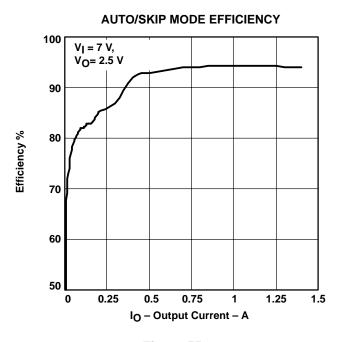


Figure 55

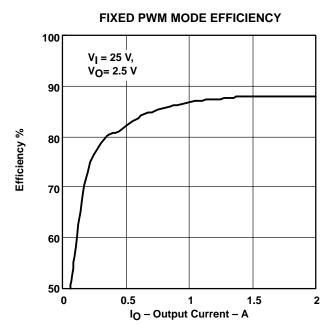


Figure 54

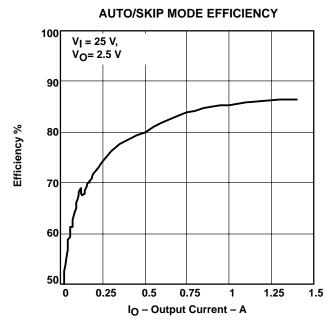
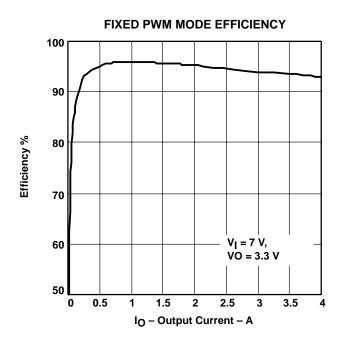


Figure 56





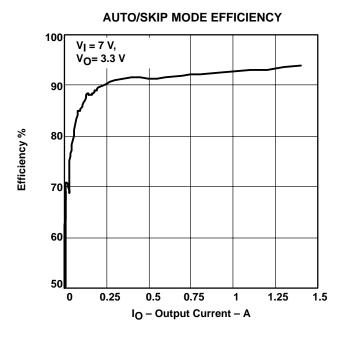


Figure 59

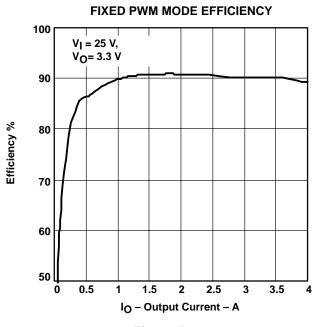


Figure 58

### **AUTO/SKIP MODE EFFICIENCY**

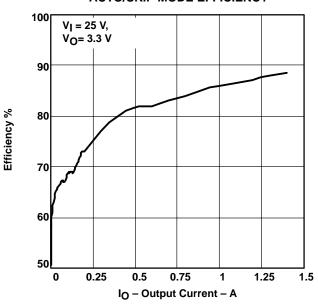


Figure 60

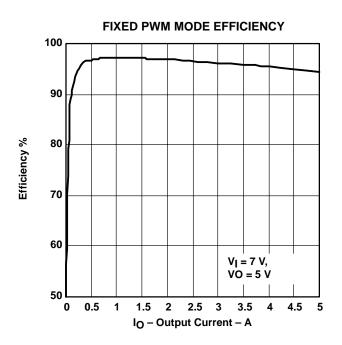


Figure 61

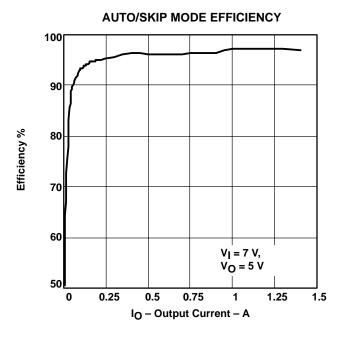


Figure 63

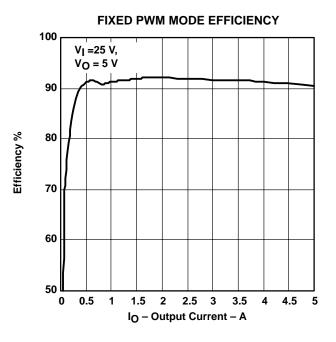


Figure 62

**AUTO/SKIP MODE EFFICIENCY** 

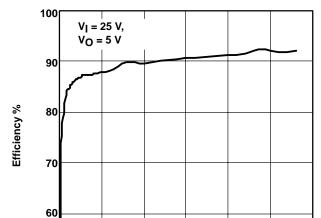


Figure 64

0.75

IO - Output Current - A

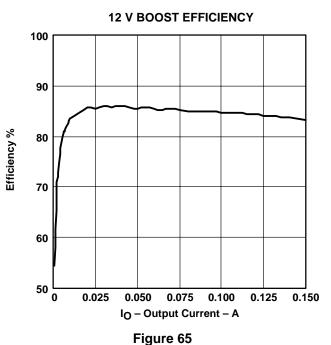
1.25

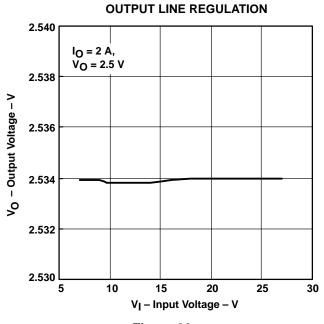
1.5

50

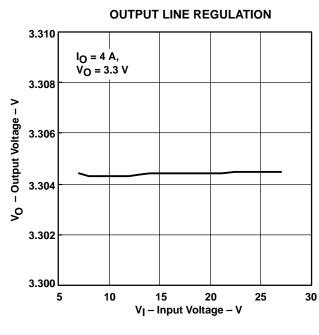
0

0.25









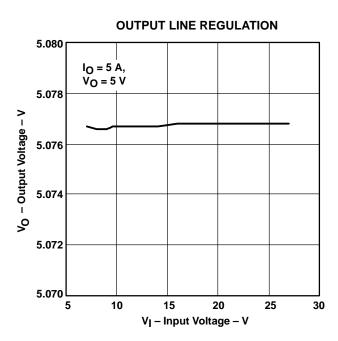


Figure 67

Figure 68

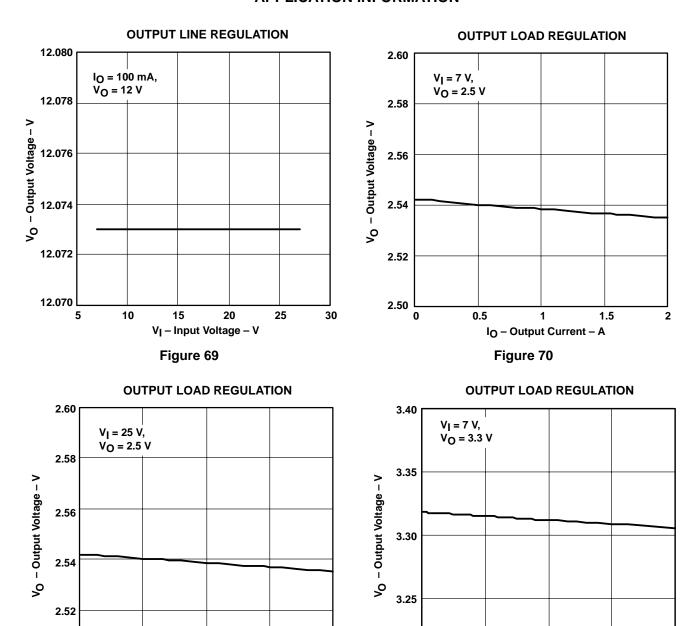


Figure 71

IO - Output Current - A

2.50

Figure 72

2

IO - Output Current - A

3

3.20

0

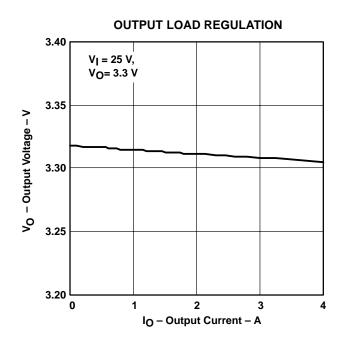


Figure 73

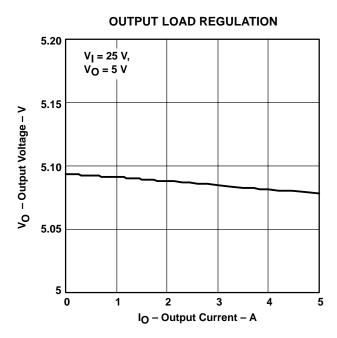


Figure 75

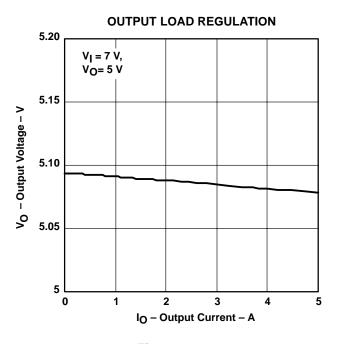


Figure 74

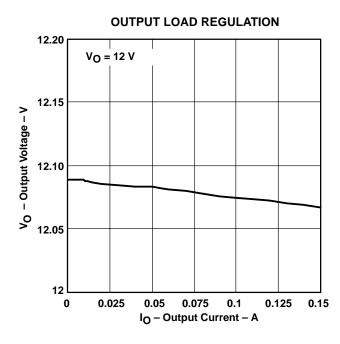
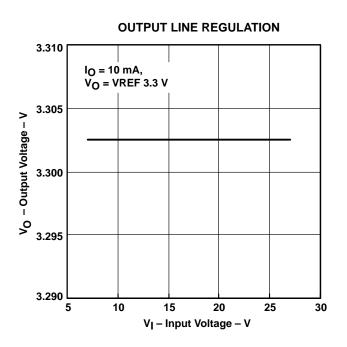


Figure 76



# 3.35 V<sub>I</sub> = 7 V, V<sub>O</sub> = VREF 3.3 V 3.33 3.30 3.30 3.28

Figure 77

Figure 78

0.02

IO - Output Current - A

0.03

0.04

0.01



3.25

0

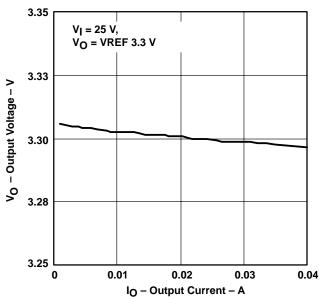


Figure 79

### 2.5 V OUTPUT VOLTAGE RIPPLE

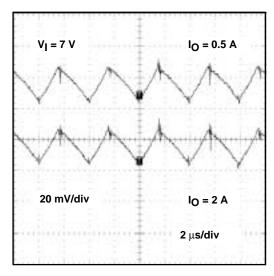


Figure 80

### **5 V OUTPUT VOLTAGE RIPPLE**

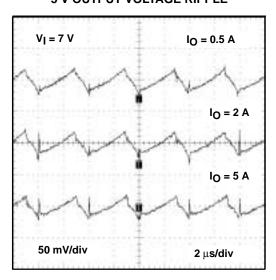


Figure 82

### 3.3 V OUTPUT VOLTAGE RIPPLE

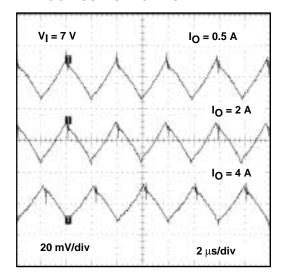


Figure 81

### 12 V OUTPUT VOLTAGE RIPPLE

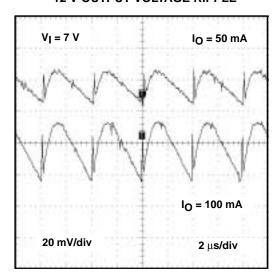


Figure 83

# 2.5 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE

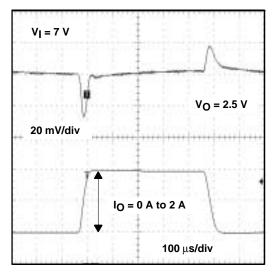


Figure 84

# 3.3 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE

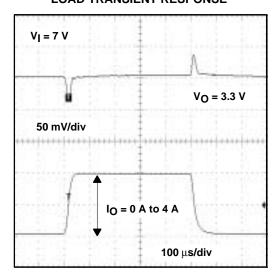


Figure 86

# 2.5 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE

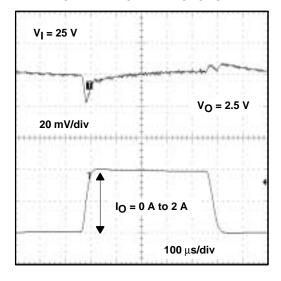


Figure 85

# 3.3 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE

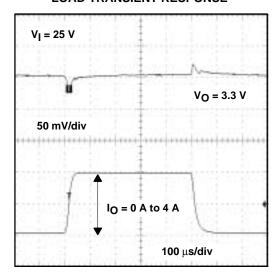
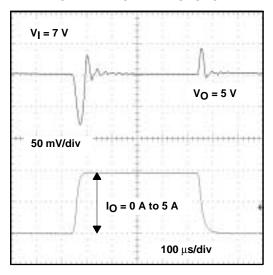


Figure 87

### 5 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE



### 5 V OUTPUT VOLTAGE LOAD TRANSIENT RESPONSE

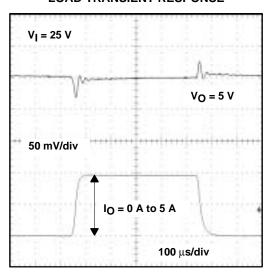


Figure 88

Figure 89

**Table 4. Bill of Materials** 

REF.	PN	DESCRIPTION	MFG.	SIZE
C01	Open	Capacitor, electrolytic, 330 μF, 35 V	Sanyo	10x10 mm
C02	Standard	Capacitor, ceramic, 2200 pF		805
C03	Standard	Capacitor, ceramic, 0.01 μF		805
C04	Standard	Capacitor, ceramic, 56 pF		805
C05	Standard	Capacitor, ceramic, 0.1 μF		805
C06	Standard	Capacitor, ceramic, 0.022 μF		805
C07	Standard	Open		805
C08	Standard	Capacitor, ceramic, 0.01 μF		805
C09	Standard	Capacitor, ceramic, 2200 pF		805
C10	Standard	Capacitor, ceramic, 1.0 μF		805
C11A	10TPB220M	Capacitor, POSCAP, 220 μF, 10 V	Sanyo	7.3x4.3 mm
C11B	Open	Open, Capacitor, POSCAP	Sanyo	7.3x4.3 mm
C12	Standard	Capacitor, ceramic, 0.1 μF		805
C13	TMK325BJ475MN-B	Capacitor, ceramic, 4.7 μF		1210 (3225)
C14	Standard	Capacitor, ceramic, 1.0 μF		805
C15A	6TPB150M	Capacitor, POSCAP, 150 μF, 6.3 V	Sanyo	7.3x4.3 mm
C15B	6TPB150M	Capacitor, POSCAP, 150 μF, 6.3 V	Sanyo	7.3x4.3 mm
C16A	10TPB220M	Capacitor, POSCAP, 220 μF, 10 V	Sanyo	7.3x4.3 mm
C16B	Open	Open, Capacitor, POSCAP	Sanyo	7.3x4.3 mm

### Table 4. Bill of Materials (Continued)

REF.	PN	DESCRIPTION	MFG.	SIZE
C17	Standard	Capacitor, ceramic, 1.0 μF		805
C18	Standard	Capacitor, ceramic, 2200 pF		805
C19	Standard	Capacitor, ceramic, 0.01 μF		805
C20	TMK432BJ106MN	Capacitor, ceramic, 10 μF, 25 V, X5R	Taiyo Yuden	1812 (432)
C21	TMK432BJ106MN	Capacitor, ceramic, 10 μF, 25 V, X5R	Taiyo Yuden	1812 (432)
C22	Standard	Capacitor, ceramic, 0.01 μF		805
C23	Standard	Open		805
C24	TMK432BJ106MN	Capacitor, ceramic, 10 μF, 25 V, X5R	Taiyo Yuden	1812 (432)
C25	TMK432BJ106MN	Capacitor, ceramic, 10 μF, 25 V, X5R	Taiyo Yuden	1812 (432)
C26	TMK432BJ106MN	Capacitor, ceramic, 10 μF, 25 V, X5R	Taiyo Yuden	1812 (432)
C27	Standard	Capacitor, ceramic, 8200 pF		805
C28	Standard	Capacitor, ceramic, 8200 pF		805
C29	Standard	Capacitor, ceramic, 6800 pF		805
C30	Standard	Capacitor, ceramic, 0.1 μF		805
C31	Standard	Capacitor, ceramic, 0.1 μF		805
C32	Standard	Capacitor, ceramic, 0.1 μF		805
D1	MBR0540T1	Diode, Schottky, 40 V, 500 mA	Motorola	3.7x1.6 mm
D2	MBR0540T1	Diode, Schottky, 40 V, 500 mA	Motorola	3.7x1.6 mm
D3	MBR0540T1	Diode, Schottky, 40 V, 500 mA	Motorola	3.7x1.6 mm
D4	RB160L-40-TE25	Diode, Schottky, 40 V, 1 A	Rohm	4.5x2.6 mm
D5	EC31QS04	Diode, Schottky, 40 V, 3 A	Nihon Inter	5.0x2.5 mm
D6	EC31QS04	Diode, Schottky, 40 V, 3 A	Nihon Inter	5.0x2.5 mm
D7	EC31QS04	Diode, Schottky, 40 V, 3 A	Nihon Inter	5.0x2.5 mm
JP00~JP06	WL-8	Header, straight, 3-pin	Mac8	
JP8	WL-8	Header, straight, 3-pin	Mac8	
JP00~JP06 shunt	JS-1	Jumper socket	Mac8	
JP8 shunt	JS-1	Jumper socket	Mac8	
L1	CDRH127-100	Inductor, 10 μH, 5.4 A	Sumida	12x12 mm
L2	CDRH127-6R1	Inductor, 6.1 μH, 6.6 A	Sumida	12x12 mm
L3	CDRH125-100	Inductor, 10 μH, 4.0 A	Sumida	12x12 mm
L4	CDRH5D28-220	Inductor, 22 µH, 0.9 A	Sumida	5.7x5.7 mm
R01A	Standard	Resistor, 15 kΩ, 1%		805
R01B	Standard	Resistor, 18 kΩ, 1%		805
R02A	Standard	Resistor, 10 kΩ, 1%		805
R02B	Standard	Open		805
R03	Standard	Resistor, 470 $\Omega$ , 5%		805
R04	Standard	Resistor, 470 Ω, 5%		805
R05A	Standard	Resistor, 10 kΩ, 1%		805
R05B	Standard	Open		805
R06A	Standard	Resistor, 1.8 kΩ, 1%		805
R06B	Standard	Resistor, 10 k $\Omega$ , 1%		805
R07	Standard	Resistor, 10 kΩ, 1%		805



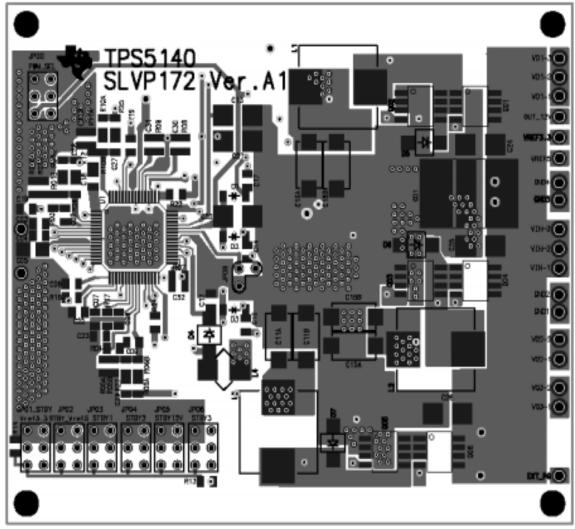
### Table 4. Bill of Materials (Continued)

REF.	PN	DESCRIPTION	MFG.	SIZE
R08	Standard	Resistor, 24 kΩ, 1%		805
R09	Standard	Resistor, 18 kΩ, 1%		805
R10A	Standard	Resistor, 2 kΩ, 1%		805
R10B	Standard	Resistor, 16 k $\Omega$ , 1%		805
R11A	Standard	Resistor, 10 k $\Omega$ , 1%		805
R11B	Standard	Open		805
R12	Standard	Resistor, 470 Ω, 5%		805
R13	Standard	Resistor, 100 kΩ, 5 %		805
R14	Standard	Open		805
R16	Standard	Resistor, 100 kΩ, 5 %		805
R17	Standard	Open		805
R19	Standard	Resistor, 15 $\Omega$ , 5 %		805
R22	Standard	Resistor, 15 Ω, 5 %		805
R24	Standard	Resistor, 15 Ω, 5 %		805
R25	Standard	Resistor, 220 Ω, 5 %		805
R26	Standard	Resistor, 470 Ω, 5 %		805
R27	Standard	Resistor, 100 Ω, 5 %		805
Q01~Q06	FDS6612A	Transistor, MOSFET, N-ch, 30 V, 8.4 A, 26 mΩ	Transistor, MOSFET, N–ch, 30 V, 8.4 A, 26 mΩ Fairchild	
U1	TPS5140	IC, Quad controller	TI	TQFP

### **Table 5. Vendor and Source Information**

MATERIAL	SOURCE	PART NUMBER	DISTRIBUTORS
MOSFETS (Q01- Q06)	In EVM design	FDS6612A (Fairchild)	Local Distributor
MOSPETS (Q01- Q00)	Second source	IRF9410 (International Rectifier)	
MAIN DIODES (D5 – D7)	In EVM design	EC31QS04 (Nihon Inter)	81-3-3342-5407
CERAMIC CAPACITORS (C20, C21, C24 , C25, C26)	In EVM design	TMK432BJ106MN (Taiyo Yuden)	http://www.t-yuden.com http://www.yuden.co.jp
INDUCTORS (L1 – L4)	In EVM design	CDRH125–100 CDRH127–6R1 CDRH127–100 CDRH5D28–220 (Sumida)	http://www.sumida.com

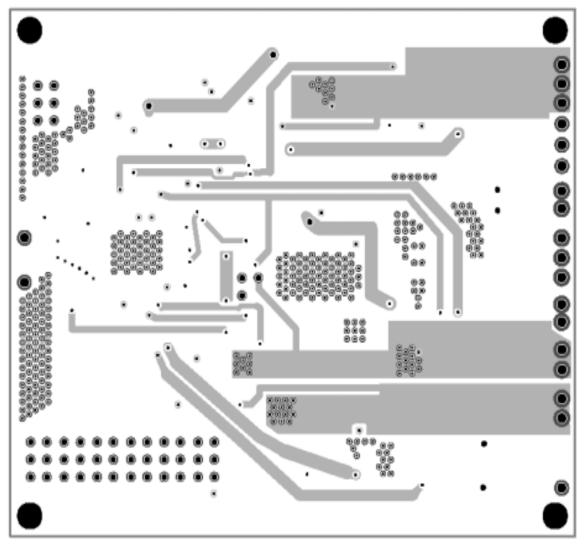
# **EVM Layout**



**Top Layer** 

Figure 90. EVM Top Layer

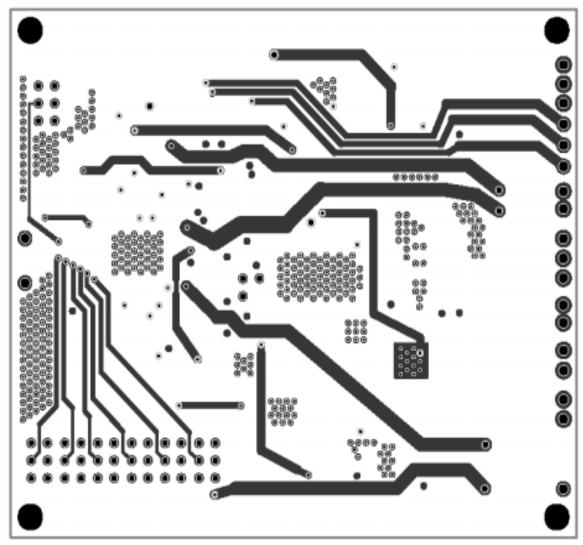
# **EVM Layout (continued)**



2nd Layer

Figure 91. EVM Second Layer

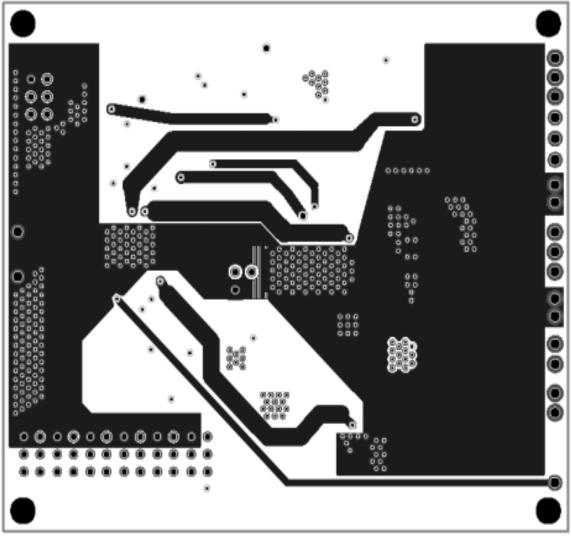
# **EVM Layout (continued)**



3rd Layer

Figure 92. EVM Third Layer

### **EVM Layout (continued)**



**Bottom Layer (Top View)** 

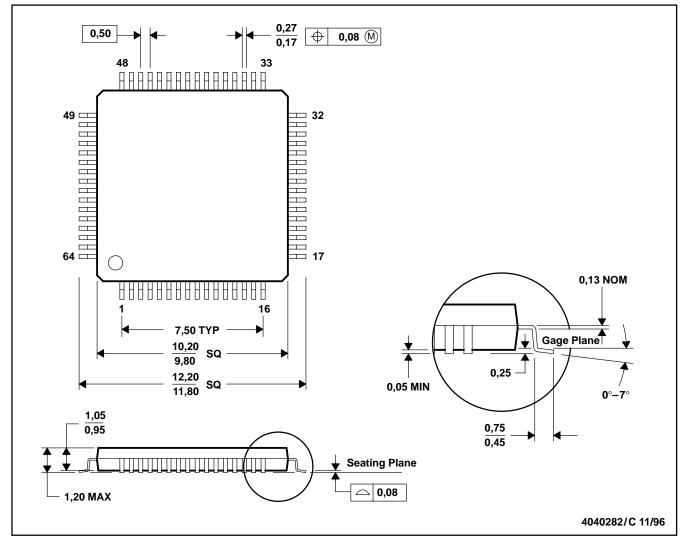
Figure 93. EVM Bottom Layer (Top View)



### **MECHANICAL DATA**

### PAG (S-PQFP-G64)

### PLASTIC QUAD FLATPACK



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-026





com 5-Oct-2007

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS5140PAG	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR
TPS5140PAGG4	ACTIVE	TQFP	PAG	64	160	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR
TPS5140PAGR	ACTIVE	TQFP	PAG	64	1500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR
TPS5140PAGRG4	ACTIVE	TQFP	PAG	64	1500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-4-260C-72 HR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

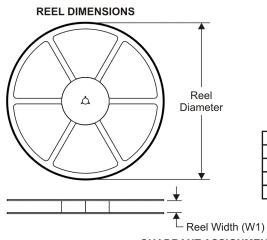
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

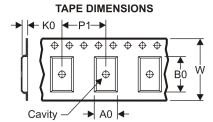
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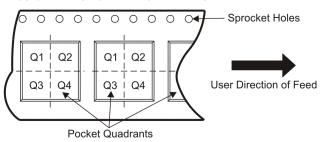
### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

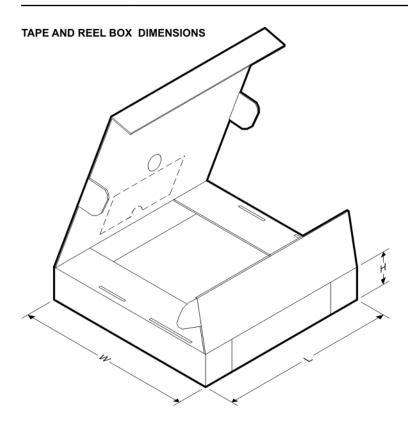
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS5140PAGR	TQFP	PAG	64	1500	330.0	24.4	13.0	13.0	1.5	16.0	24.0	Q2





### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS5140PAGR	TQFP	PAG	64	1500	346.0	346.0	41.0

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